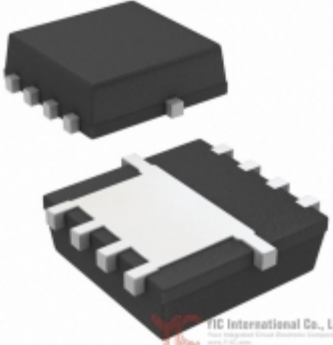

	<h2 style="color: red;">SI7621DN-T1-GE3</h2>
	Hersteller-Teilenummer: SI7621DN-T1-GE3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET P-CH 20V 4A 1212-8 PPAK
	Datenblätter:  SI7621DN-T1-GE3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 54980 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7621DN-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 20V 4A 1212-8 PPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	54980 pcs Stock
detaillierte Beschreibung	P-Channel 20V 4A (Tc) 3.1W (Ta), 12.5W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® 1212-8
Supplier Device-Gehäuse	PowerPAK® 1212-8
Verlustleistung (max)	3.1W (Ta), 12.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A (Tc)
Rds On (Max) @ Id, Vgs	90 mOhm @ 3.9A, 4.5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.2nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	300pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI7621DN-T1-GE3TR

SI7621DN-T1-GE3 ist neu im Original, Suche SI7621DN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7621DN-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7621DN-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7620DN-T1-GE3 Vishay / Siliconix MOSFET N-CH 150V 13A 1212-8</p>	 <p>SI7621DN-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 4A 1212-8 PPAK</p>	 <p>SI7623DN-T1-E3 VISHAY VISHAY PAK1212</p>	 <p>SI7621DN VISHAY SI7621DN VISHAY</p>
 <p>SI7625DN-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 35A 1212-8 PPAK</p>	 <p>SI7623DN-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 35A 1212-8</p>	 <p>SI7625DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 35A 1212-8 PPAK</p>	 <p>SI7620DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 13A 1212-8</p>

heiße Teile

Mehr

SI7491DP-T1-GE3	SI7501DN-T1-E3	SI7501DN-T1-E3	SI7540ADP-T1-GE3	SI7540ADP-T1-GE3
SI7540DP-T1-E3	SI7540DP-T1-E3	SI7540DP-T1-GE3	SI7540DP-T1-GE3	SI7606DN-T1-E3
SI7606DN-T1-GE3	SI7611DN-T1-GE3	SI7611DN-T1-GE3	SI7613DN-T1-GE3	SI7613DN-T1-GE3
SI7615ADN-T1-GE3	SI7615ADN-T1-GE3	SI7615DN	SI7615DN-T1-E3	SI7615DN-T1-GE3
SI7615DN-T1-GE3	SI7617DN-T1-GE3	SI7617DN-T1-GE3	SI7619DN-T1-GE3	SI7619DN-T1-GE3
SI7621DN-T1-GE3	SI7625DN-T1-GE3	SI7625DN-T1-GE3	SI7629DN-T1	SI7629DN-T1-GE3
SI7629DN-T1-GE3	SI7633DP-T1-GE3	SI7633DP-T1-GE3	SI7634BDP	SI7634BDP-T1-E3
SI7634BDP-T1-E3	SI7634BDP-T1-GE3	SI7634BDP-T1-GE3	SI7634DP-T1-E3	SI7634DP-T1-GE3
SI7635DP	SI7635DP-T1-GE3	SI7635DP-T1-GE3	SI7636DP	SI7636DP-T1-E3
SI7636DP-T1-E3	SI7636DP-T1-GE3	SI7636DP-T1-GE3	SI7637DP-T1-E3	SI7652DP-T1-E3

Contact us: Info@Y-IC.com

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